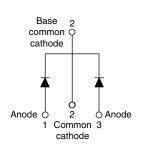


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Schottky Rectifier, 2 x 15 A

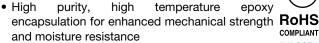


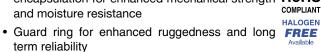


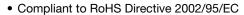
PRODUCT SUMMARY					
Package	TO-220AB				
I _{F(AV)}	2 x 15 A				
V_{R}	25 V, 30 V				
V _F at I _F	0.40 V				
I _{RM} max.	97 mA at 125 °C				
T _J max.	150 °C				
Diode variation	Common cathode				
E _{AS}	13 mJ				

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation







- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The VS-32CTQ... Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	30	А			
V_{RRM}		25/30	V			
I _{FSM}	t _p = 5 μs sine	900	Α			
V _F	15 A _{pk} , T _J = 125 °C	0.40	V			
T_J	Range	- 55 to 150	°C			

VOLTAGE RATINGS						
PARAMETER SYMBOL VS-32CTQ025PbF VS-32CTQ025-N3 VS-32CTQ030PbF VS-32CTQ030-N3 U					UNITS	
Maximum DC reverse voltage	V_{R}	25	25	30	30	V
Maximum working peak reverse voltage	V_{RWM}	23	25	30	30	`

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS	
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 115 °C	30			
Maximum peak one cycle non-repetitive surge current	1	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	900	Α	
See fig. 7			V _{RRM} applied	250		
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.20 \text{A}, L = 11.10 \text{mH}$		13	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		3	Α	



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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		15 A	T 05 °C	0.49	V	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	30 A	T _J = 25 °C	0.58		
See fig. 1	V _{FM} ('')	15 A	T 105 %C	0.40		
		30 A	T _J = 125 °C	0.53		
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V Doted V	1.75	mA	
See fig. 2	'RM '''	T _J = 125 °C	V _R = Rated V _R	97		
Threshold voltage	V _{F(TO)}	T T manyimayina		0.233	V	
Forward slope resistance	r _t	$T_J = T_J$ maximum		9.09	mΩ	
Maximum junction capacitance per leg	C _T	V _R = 5 V _{DC} (test signal rang	1300	pF		
Typical series inductance per leg	L _S	Measured lead to lead 5 m	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V _R 10 000			V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL TEST CONDITIONS		VALUES	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 150	°C		
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation See fig. 4	3.25	0000		
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	°C/W		
Approximate weight			2	g		
Approximate weight			0.07	OZ.		
Mounting torque minimum			6 (5)	kgf · cm		
Mounting torque maximum			12 (10)	(lbf \cdot in)		
Modern device		Coop ob lo TO 200AB	32CTQ025			
Marking device		Case style TO-220AB	32CTQ030			

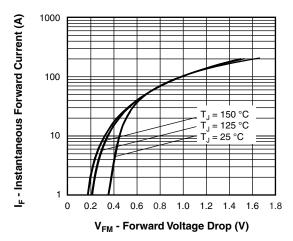


Fig. 1 - Maximum Forward Voltage Drop Characteristics

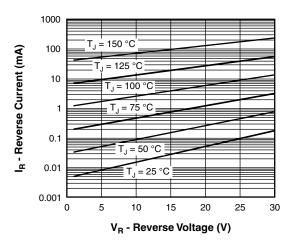


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

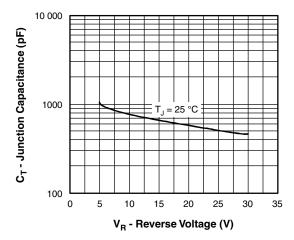


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

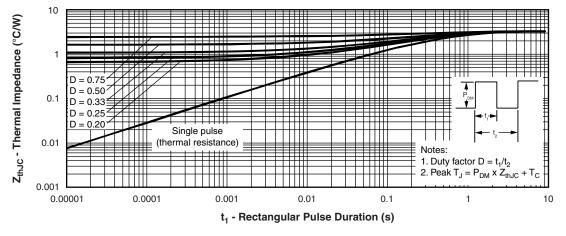


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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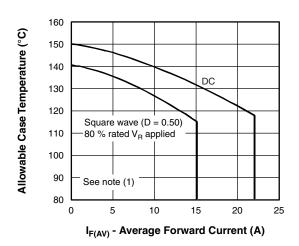


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

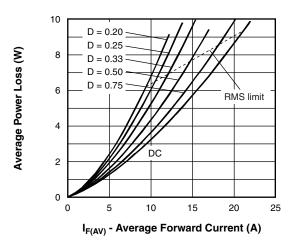


Fig. 6 - Forward Power Loss Characteristics

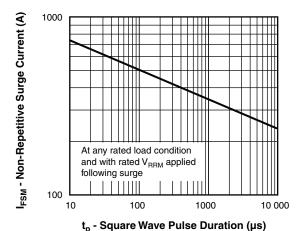


Fig. 7 - Maximum Non-Repetitive Surge Current

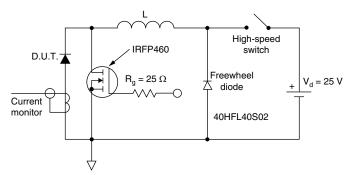


Fig. 8 - Unclamped Inductive Test Circuit

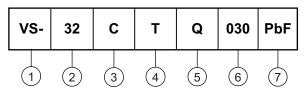
Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Current rating (30 A)

3 - Circuit configuration:

C = Common cathode

4 - Package:

T = TO-220

5 - Schottky "Q" series

6 - Voltage ratings - 025 = 25 V 030 = 30 V

7 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-32CTQ025PbF	50	1000	Antistatic plastic tube			
VS-32CTQ025-N3	50	1000	Antistatic plastic tube			
VS-32CTQ030PbF	50	1000	Antistatic plastic tube			
VS-32CTQ030-N3	50	1000	Antistatic plastic tube			

LINKS TO RELATED DOCUMENTS					
Dimensions <u>www.vishay.com/doc?95222</u>					
Dort marking information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			



Vishay Semiconductors

TO-220AB

DIMENSIONS in millimeters and inches



Lead assignments

Diodes

- 1. Anode/open
- 2. Cathode
- 3. Anode

Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° t	o 93°	
		•	•	•	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



Legal Disclaimer Notice

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